

2N7000-G

N-Channel

RoHS Device

V(BR)DSS	RDS(on)MAX	ID
60V	5Ω @ 10V	200mA
	6Ω @ 4.5V	



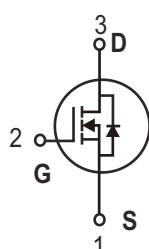
Features

- High density cell design for low R_{DS(ON)}.
- Voltage controlled small signal switch.
- Rugged and reliable.
- High saturation current capability.

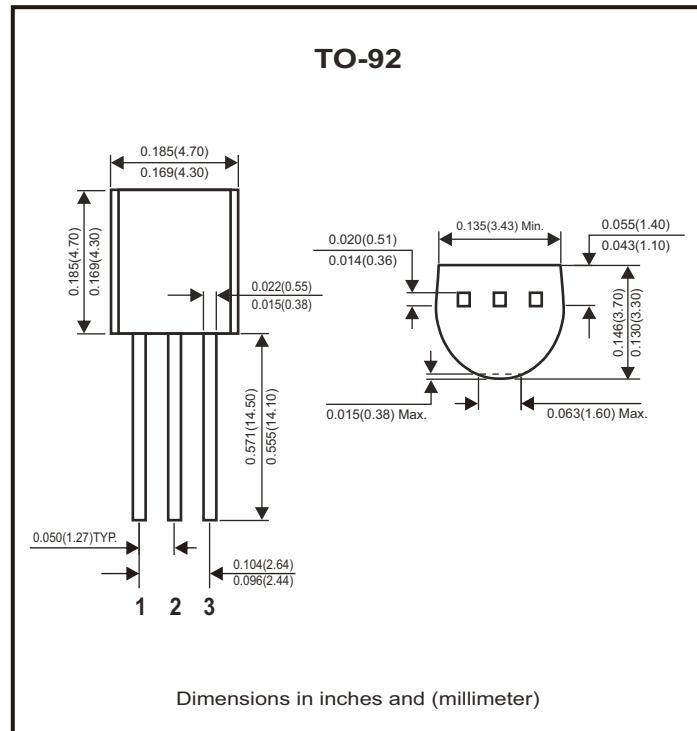
Mechanical data

- Case: TO-92, molded plastic.
- Terminals: Solderable per MIL-STD-750, method 2026.

Circuit Diagram



1. S : Source
2. G : Gate
3. D : Drain



Maximum Ratings (at TA=25°C unless otherwise noted)

Parameter	Conditions	Symbol	Value	Unit
Drain-Source voltage		V _{DS}	60	V
Continuous drain current		I _D	0.2	A
Power dissipation		P _D	0.625	W
Thermal resistance	Junction to ambient	R _{θJA}	200	°C/W
Junction temperature range		T _J	150	°C
Storage temperature range		T _{STG}	-55 to +150	°C

Electrical Characteristics (at TA=25°C unless otherwise noted)

Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Drain-source breakdown voltage	V _{GS} =0V, I _D =10μA	V _{BR(DSS)}	60			V
Gate-threshold voltage*	V _{DS} =V _{GS} , I _D =1mA	V _{th(GS)}	0.8		3	V
Gate-body leakage	V _{DS} =0V, V _{GS} =±15V	I _{GSS}			±10	nA
Zero gate voltage drain current	V _{DS} =60V, V _{GS} =0V	I _{DSS}			1	μA
On-state drain current	V _{GS} =4.5V, V _{DS} =10V	I _{D(ON)}	75			mA
Drain-source on resistance*	V _{GS} =4.5V, I _D =75mA	R _{D(S)(ON)}			6	Ω
	V _{GS} =10V, I _D =500mA				5	
Forward trans conductance*	V _{DS} =10V, I _D =200mA	g _{fs}	100			mS
Drain-source on-voltage*	V _{GS} =10V, I _D =500mA	V _{D(S)(ON)}			2.5	V
	V _{GS} =4.5V, I _D =75mA				0.45	
Input capacitance **	V _{DS} =25V, V _{GS} =0V, f=1MHz	C _{iss}			60	pF
Output capacitance **		C _{oss}			25	
Reverse transfer capacitance **		C _{rss}			5	
Turn-on time **	V _{DD} =15V, R _L =30Ω, I _D =500mA, V _{GGEN} =10V, R _G =25Ω	t _{d(on)}			10	nS
Turn-off time **		t _{d(off)}			10	

Note: * Pulse test

** These parameters have no way to verify

RATING AND CHARACTERISTIC CURVES (2N7000-G)

Fig.1 - Output Characteristics

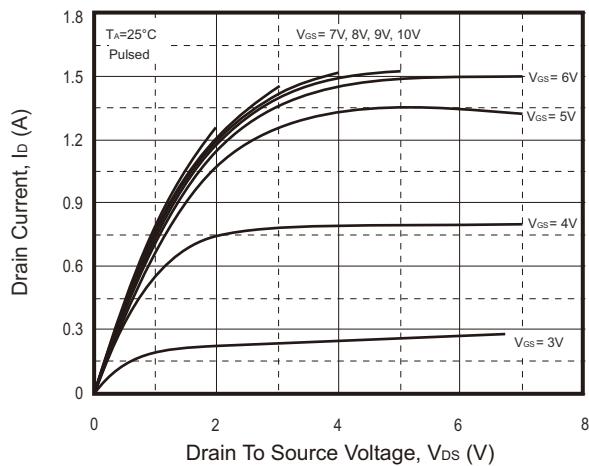


Fig.2 - Transfer Characteristics

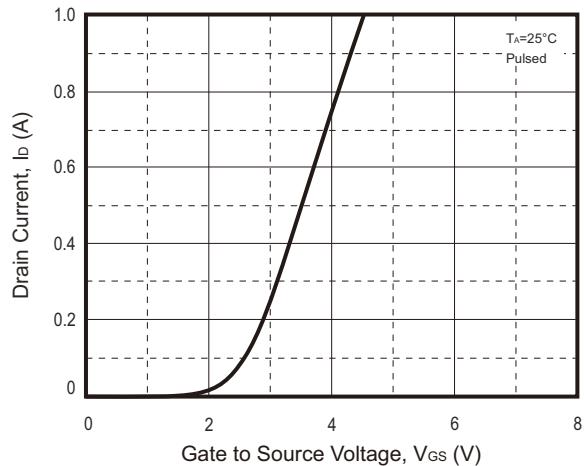


Fig.3 - $R_{DS(ON)}$ — I_D

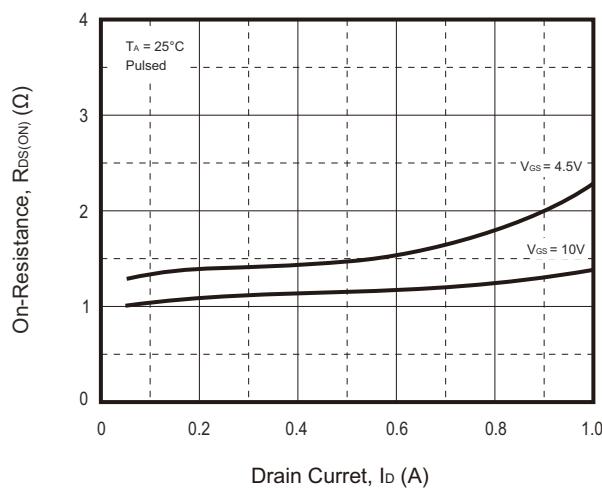


Fig.4 - $R_{DS(ON)}$ — V_{GS}

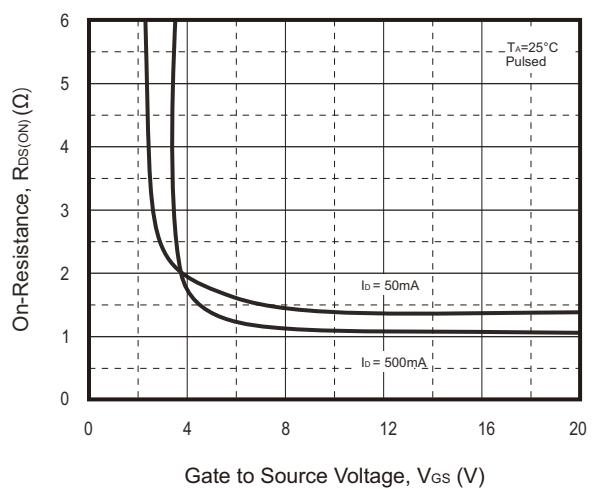
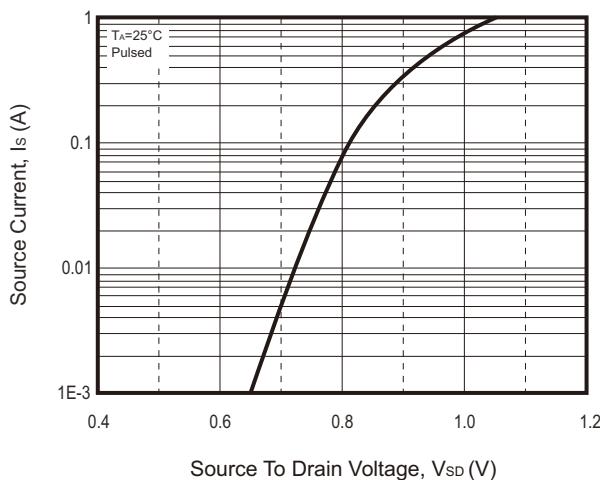
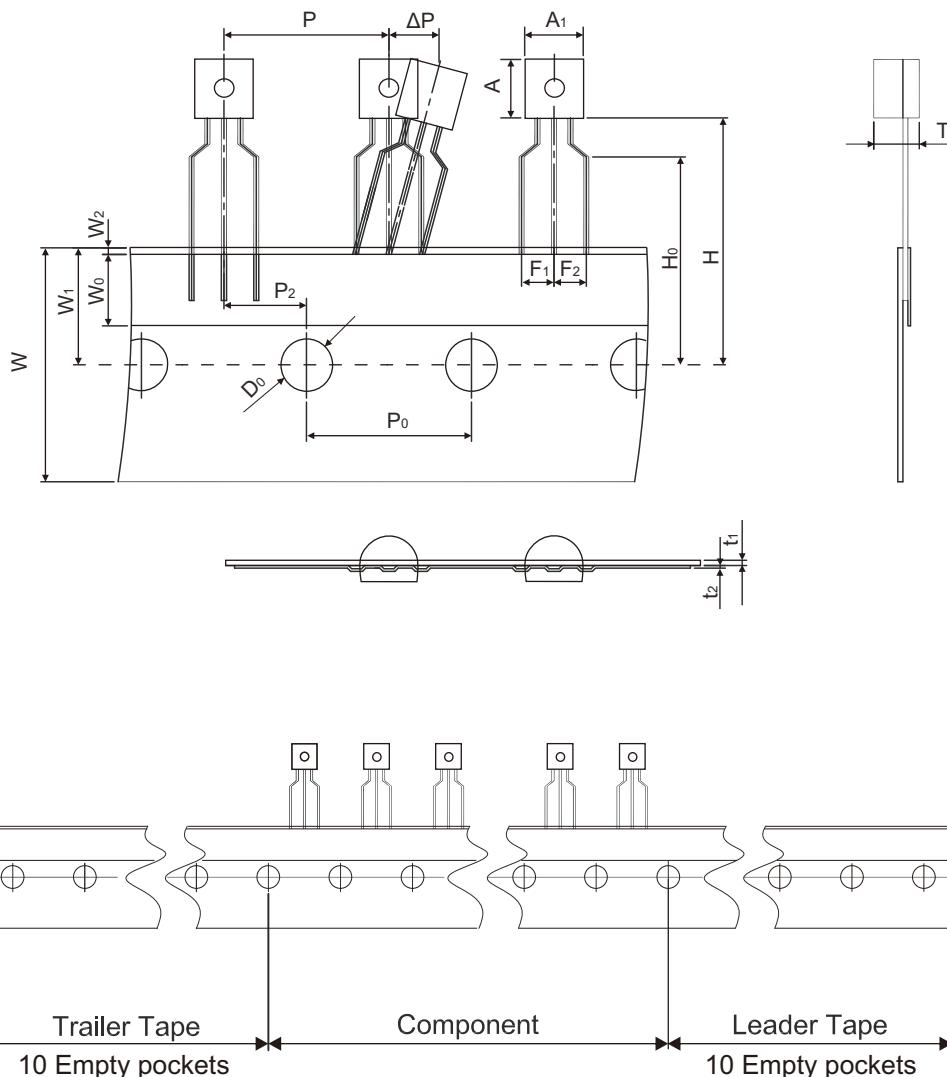


Fig.5 - I_S — V_{SD}



Reel Taping Specification

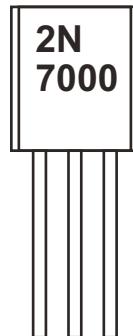


TO-92	SYMBOL	A ₁	A	T	P	P ₀	P ₂	F ₁	F ₂	W
	(mm)	4.50 ± 0.20	4.50 ± 0.20	3.50 ± 0.20	12.70 ± 0.30	12.70 ± 0.20	6.35 ± 0.30	2.50 ± 0.30	2.50 ± 0.30	18.00 ± 1.00 - 0.50
	(inch)	0.177 ± 0.008	0.177 ± 0.008	0.138 ± 0.008	0.500 ± 0.012	0.500 ± 0.008	7.008 ± 0.039	0.098 ± 0.039	0.098 ± 0.012	0.709 ± 0.040 - 0.020

TO-92	SYMBOL	W ₀	W ₁	W ₂	H	H ₀	D ₀	t ₁	t ₂	ΔP
	(mm)	6.00 ± 0.50	9.00 ± 0.50	1.00 Max.	19.00 ± 2.00 - 1.00	16.00 ± 0.50	4.00 ± 0.20	0.40 ± 0.05	0.20 ± 0.05	0.00 ± 0.10
	(inch)	0.236 ± 0.020	0.354 ± 0.020	0.039 Max.	0.748 ± 0.079 - 0.039	0.630 ± 0.020	0.157 ± 0.008	0.016 ± 0.002	0.008 ± 0.002	0.000 ± 0.004

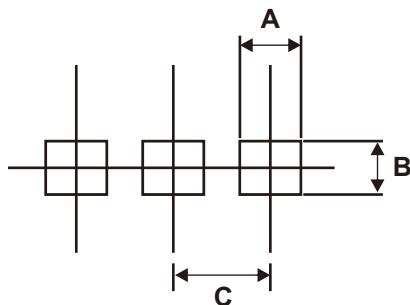
Marking Code

Part Number	Marking Code
2N7000-G	2N7000



Suggested PAD Layout

SIZE	TO-92	
	(mm)	(inch)
A	0.80	0.031
B	0.70	0.028
C	1.27	0.050



Standard Packaging

Case Type	AMMO PACK
	BOX (pcs)
TO-92	2,000